NSN 5961-01-377-0916

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-377-0916 **Inclosure Material:** Ceramic or glass **Overall Length:** 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.092 inches and 0.104 inches **Mounting Method:** Terminal **Features Provided:** Burn in **Cubic Measure:** 0.010 cubic inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 35.0 breakdown voltage, dc **Current Rating Per Characteristic:** 100.00 milliamperes forward current, total rms peak **Capacitance Rating In Picofarads:** 52.5 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 80063-a3012733 manufacturers source control Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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